

SFH 4775S

SYNIOS® P2720

IR SYNIOS P2720 (940 nm) - 120°



Applications

- CCTV Surveillance
- Eye Tracking

Features:

- Package: clear silicone
- Corrosion Robustness Class: 3B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- IR lightsource with high efficiency
- Double stack emitter
- Low thermal resistance (Max. 9 K/W)
- Centroid wavelength 940 nm

Ordering Information

Type	Total radiant flux ¹⁾ $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ Φ_e	Total radiant flux ¹⁾ typ. $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ Φ_e	Ordering Code
SFH 4775S	900 ... 1800 mW	1,150 mW	Q65112A7448

Maximum Ratings

$T_A = 25\text{ °C}$

Parameter	Symbol		Values
Operating temperature	T_{op}	min. max.	-40 °C 100 °C
Storage temperature	T_{stg}	min. max.	-40 °C 100 °C
Junction temperature	T_j	max.	145 °C
Forward current	I_F	max.	1500 mA
Surge current $t_p \leq 1.5\text{ ms}; D = 0.005$	I_{FSM}	max.	3 A
Reverse current ²⁾	I_R	max.	200 mA
Power consumption	P_{tot}	max.	5800 mW
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}	max.	2 kV

For the forward current and power consumption please see “maximum permissible forward current” diagram

Characteristics

$I_F = 1000 \text{ mA}$; $t_p = 10 \text{ ms}$; $T_A = 25 \text{ °C}$

Parameter	Symbol		Values
Peak wavelength	λ_{peak}	typ.	950 nm
Centroid wavelength	$\lambda_{\text{centroid}}$	typ.	940 nm
Spectral bandwidth at 50% $I_{\text{rel,max}}$	$\Delta\lambda$	typ.	37 nm
Half angle	φ	typ.	60 °
Dimensions of active chip area	L x W	typ.	1 x 1 mm x mm
Rise time (10% / 90%) $I_F = 3 \text{ A}$; $R_L = 50 \text{ }\Omega$	t_r	typ.	11 ns
Fall time (10% / 90%) $I_F = 3 \text{ A}$; $R_L = 50 \text{ }\Omega$	t_f	typ.	14 ns
Forward voltage	V_F	typ. max.	2.8 V 3.6 V
Forward voltage $I_F = 1.5 \text{ A}$; $t_p = 100 \text{ }\mu\text{s}$	V_F	typ. max.	2.95 V 3.85 V
Forward voltage $I_F = 3 \text{ A}$; $t_p = 100 \text{ }\mu\text{s}$	V_F	typ. max.	3.3 V 4.7 V
Reverse voltage ²⁾ $I_R = 20 \text{ mA}$	V_R	max.	1.2 V
Reverse voltage (ESD device) ²⁾	V_{RESD}	min.	5 V
Radiant intensity	I_e	typ.	360 mW/sr
Radiant intensity $I_F = 1.5 \text{ A}$; $t_p = 100 \text{ }\mu\text{s}$	I_e	typ.	545 mW/sr
Total radiant flux ¹⁾ $I_F = 1.5 \text{ A}$; $t_p = 100 \text{ }\mu\text{s}$	Φ_e	typ.	1720 mW
Temperature coefficient of voltage	TC_V	typ.	-2 mV / K
Temperature coefficient of brightness	TC_I	typ.	-0.3 % / K
Temperature coefficient of wavelength	TC_λ	typ.	0.3 nm / K
Thermal resistance junction solder point real ³⁾	R_{thJS}	max.	9.0 K / W

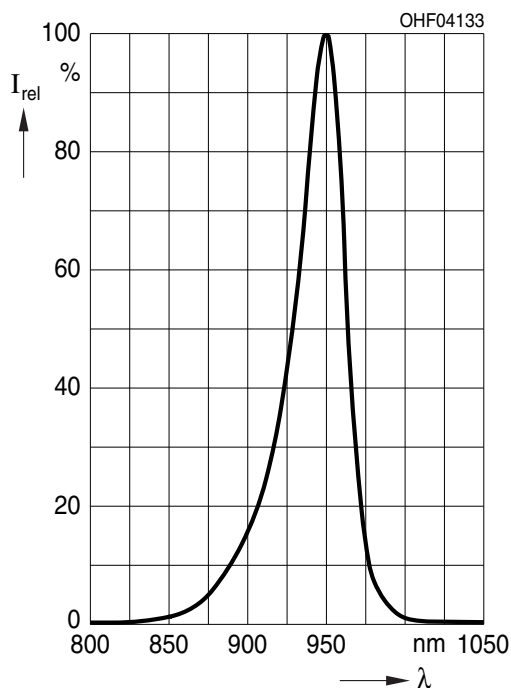
Brightness Groups

Group	Total radiant flux ¹⁾ $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ min. Φ_e	Total radiant flux ¹⁾ $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ max. Φ_e
EB2	900 mW	1250 mW
FA1	1000 mW	1400 mW
FA2	1120 mW	1600 mW
FB1	1250 mW	1800 mW

Only one group in one packing unit (variation lower 1.6:1).

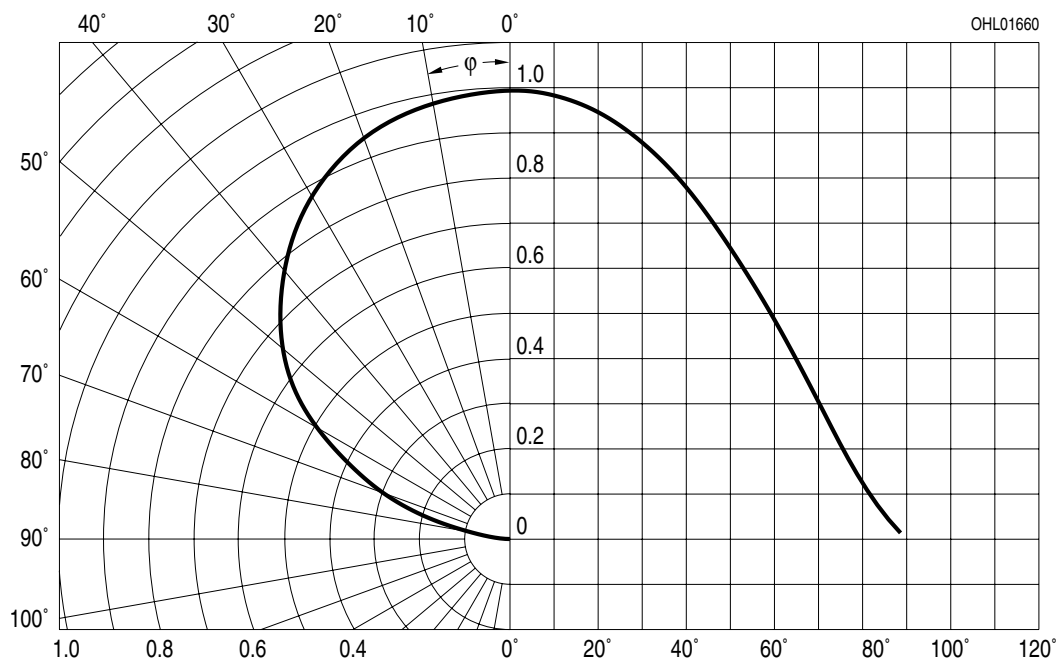
Relative Spectral Emission ^{4), 5)}

$$I_{e,rel} = f(\lambda); I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$$



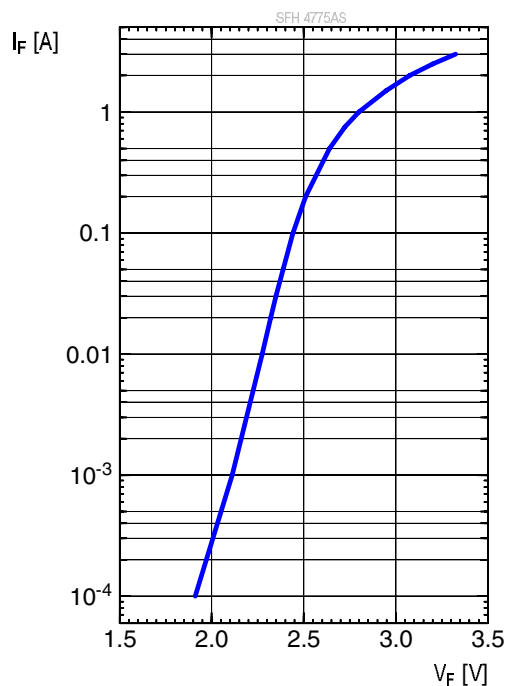
Radiation Characteristics ^{4), 5)}

$$I_{e,rel} = f(\varphi)$$



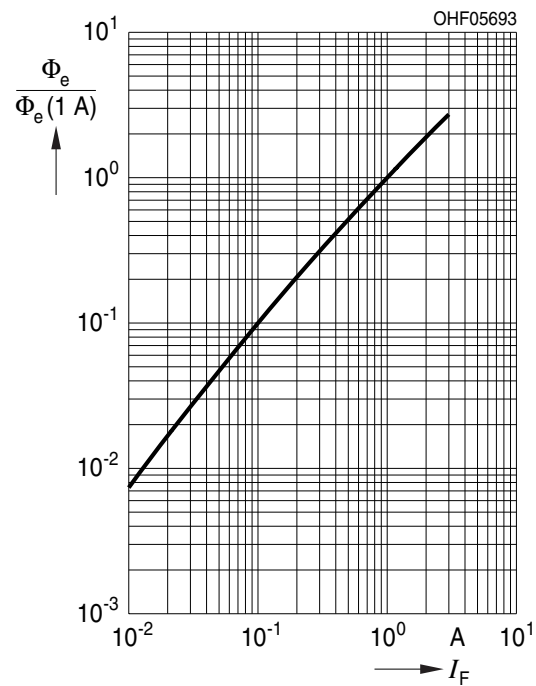
Forward current ^{4), 5)}

$$I_F = f(V_F); \text{ single pulse; } t_p = 100 \mu s$$



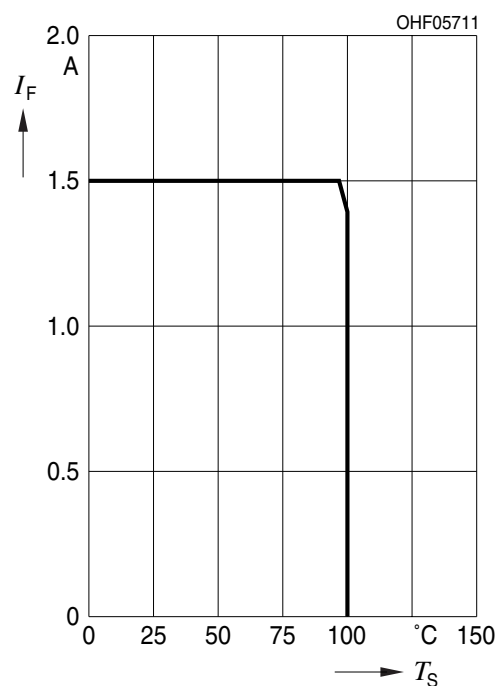
Relative Total Radiant Flux ^{4), 5)}

$$\Phi_e / \Phi_e(1000 \text{ mA}) = f(I_F); \text{ single pulse; } t_p = 100 \mu s$$



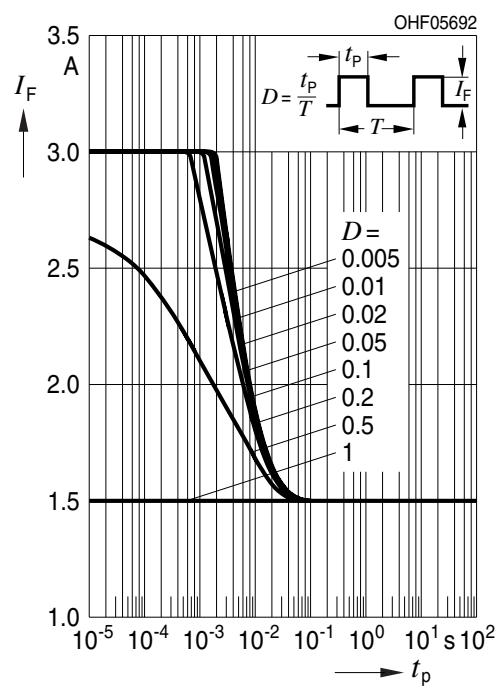
Max. Permissible Forward Current

$$I_{F,max} = f(T_S); R_{thJS} = 9.0 \text{ K/W}$$

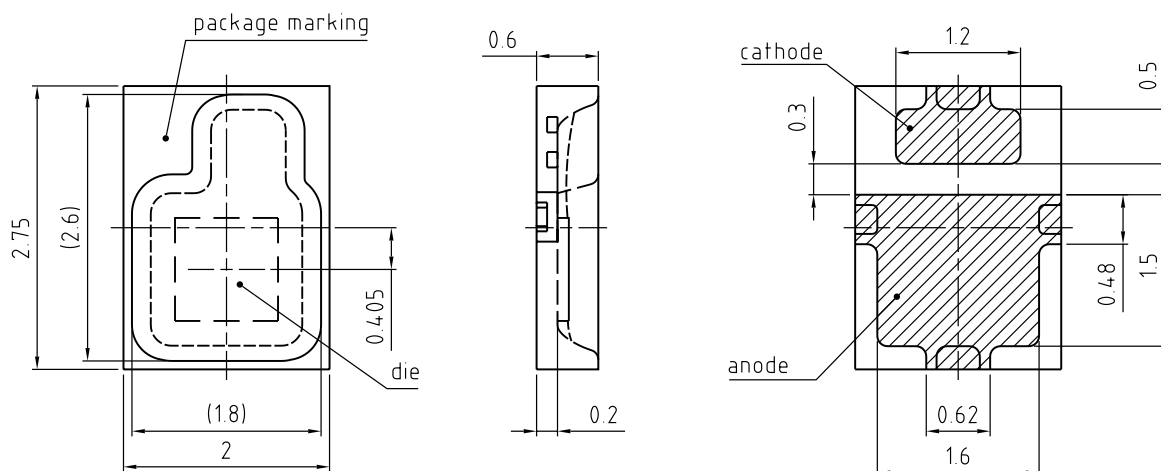


Permissible Pulse Handling Capability

$$I_F = f(t_p); \text{ duty cycle } D = \text{parameter}; T_S = 85^\circ\text{C}$$



Dimensional Drawing ⁶⁾



General tolerance ± 0.1

Lead finish Au 

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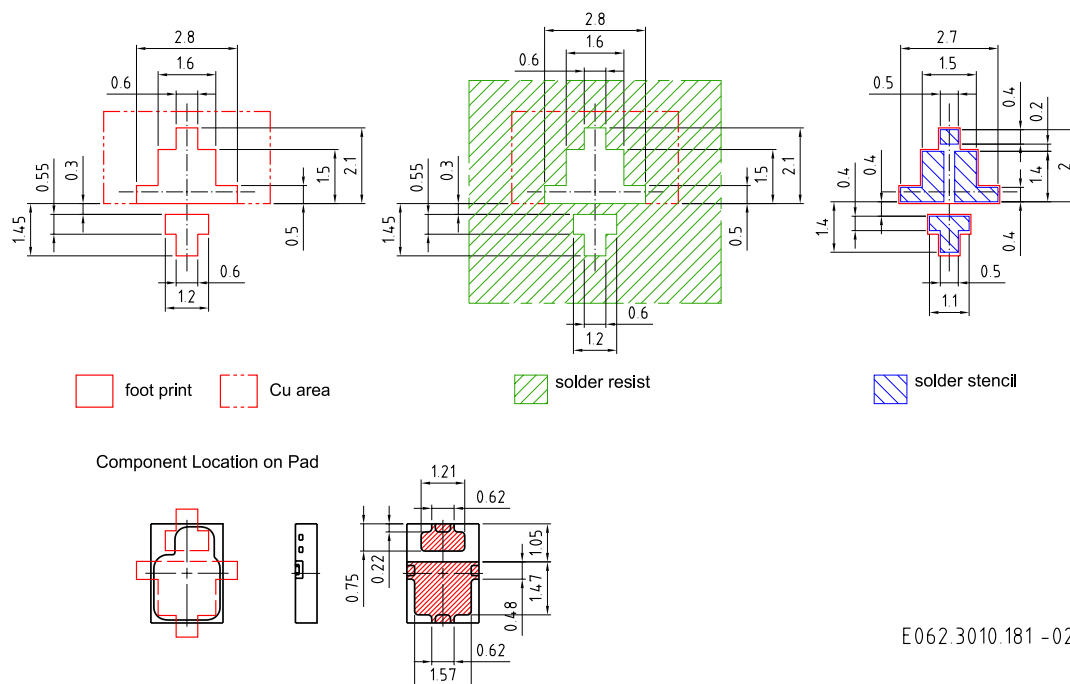
Approximate Weight: 12.0 mg

Package marking: Cathode

Corrosion test: Class: 3B
 Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC 60068-2-43)

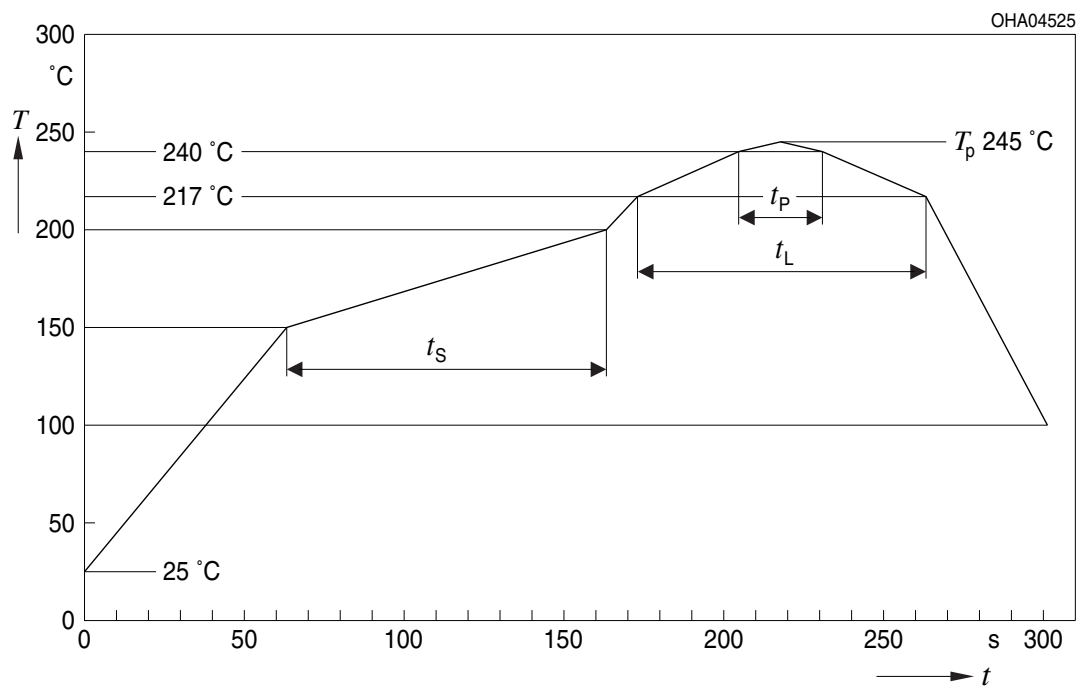
ESD advice: The device is protected by ESD device which is connected in parallel to the Chip.

Recommended Solder Pad ⁶⁾



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

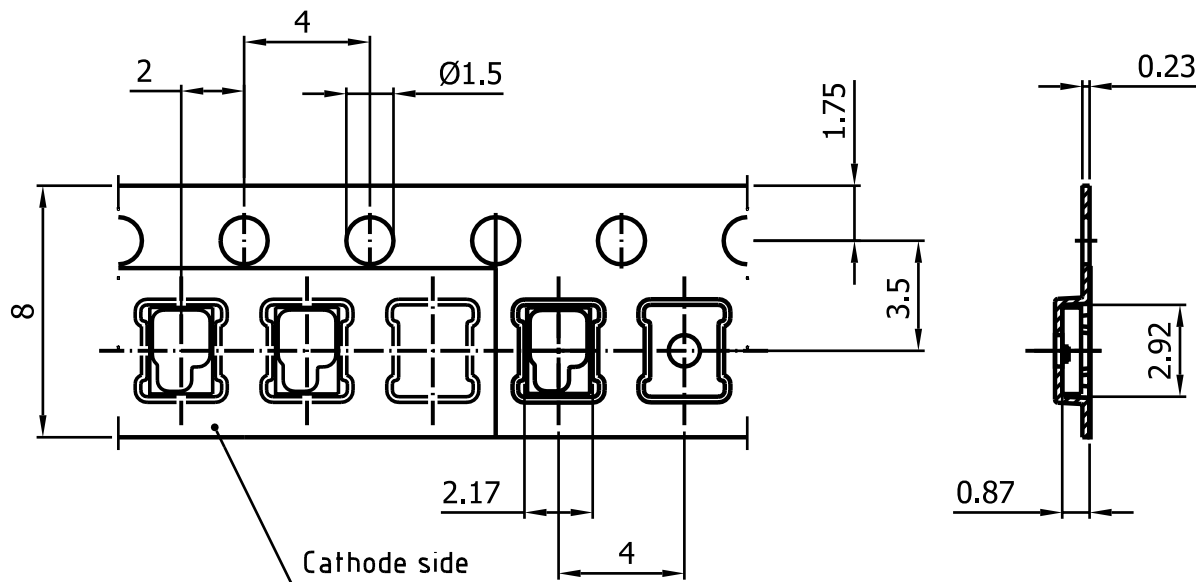


Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat ^{*)} 25 °C to 150 °C			2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t_s	60	100	120	s
Ramp-up rate to peak ^{*)} T_{Smax} to T_p			2	3	K/s
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	t_L		80	100	s
Peak temperature	T_p		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5$ K	t_p	10	20	30	s
Ramp-down rate [*] T_p to 100 °C			3	6	K/s
Time 25 °C to T_p				480	s

All temperatures refer to the center of the package, measured on the top of the component

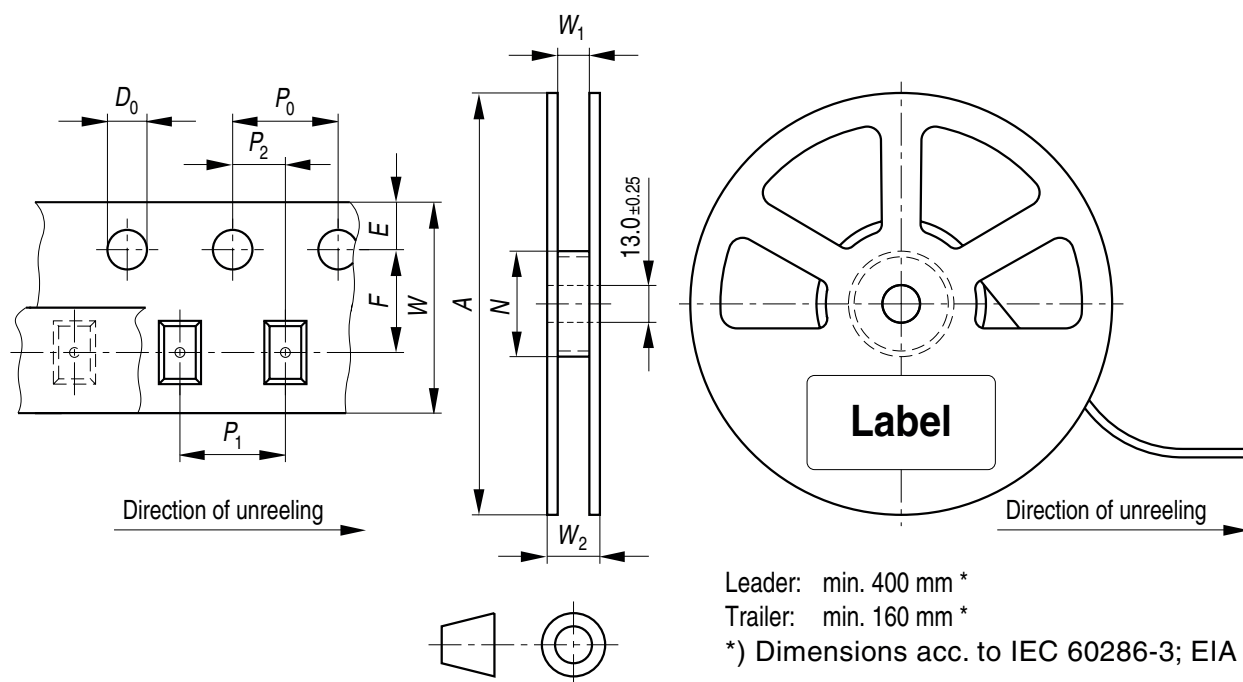
* slope calculation DT/Dt : Dt max. 5 s; fulfillment for the whole T-range

Taping ⁶⁾



C67062-A0116-B14-04

Tape and Reel ⁷⁾



Reel dimensions [mm]

A	W	N _{min}	W ₁	W _{2 max}	Pieces per PU
180 mm	8 + 0.3 / - 0.1	60	8.4 + 2	14.4	2000

Barcode-Product-Label (BPL)

OSRAM Opto Semiconductors

LX XXXX BIN1: XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890

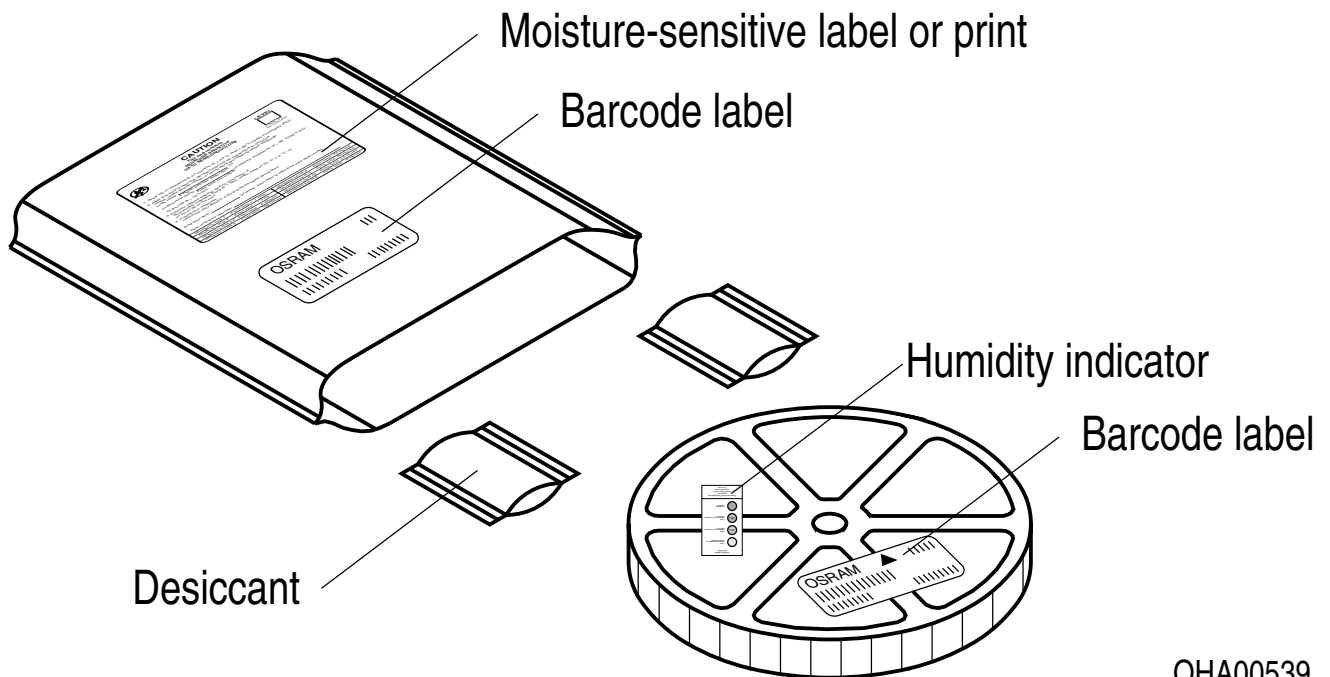
(1T) LOT NO: 1234567890 (9D) D/C: 1234

ML Temp ST
X XXX °C X

Pack: RXX
DEMY XXX
X_X123_1234.1234 X

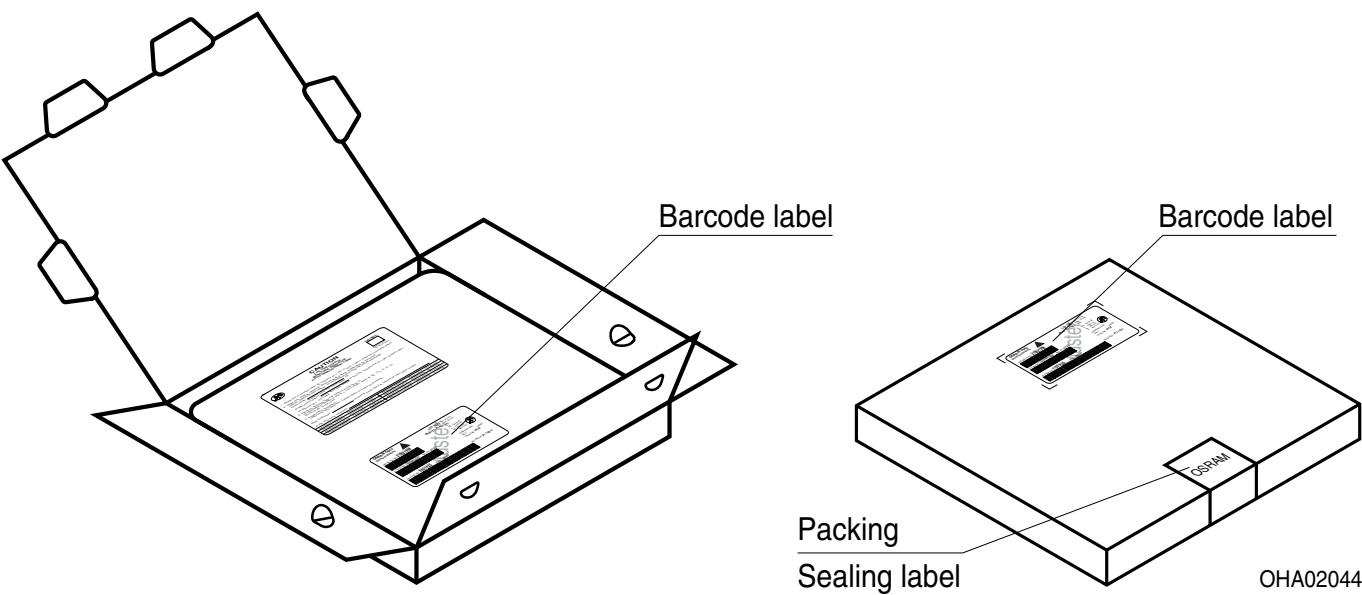
(X) PROD NO: 123456789 (Q) QTY: 9999 (G) GROUP: XX-XX-X-X

OHA04563

Dry Packing Process and Materials ⁶⁾

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

Transportation Packing and Materials ⁶⁾



Dimensions of transportation box in mm

Width	Length	Height
200 ± 5 mm	195 ± 5 mm	30 ± 5 mm

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit www.osram-os.com/apnotes

Disclaimer

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the OSRAM OS Website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.

Glossary

- 1) **Total radiant flux:** Measured with integrating sphere.
- 2) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 3) **Thermal resistance:** junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- 4) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 5) **Testing temperature:** TA = 25°C
- 6) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.
- 7) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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